## NSN 5961-01-116-6503

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-116-6503 **Inclosure Material:** Ceramic **Overall Length:** Between 0.515 inches and 0.565 inches **Overall Diameter:** Between 1.600 inches and 1.656 inches **End Application:** 4931-00-951-5308 19200 **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 25.00 milliamperes forward current, average nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

**Fiig:** A110a0